

Electronic Supplementary Information for:
**Adsorption of III/V ions (In(III), Ga(III) and As(V)) to SiO₂, CeO₂
and Al₂O₃ nanoparticles used in the semiconductor industry**

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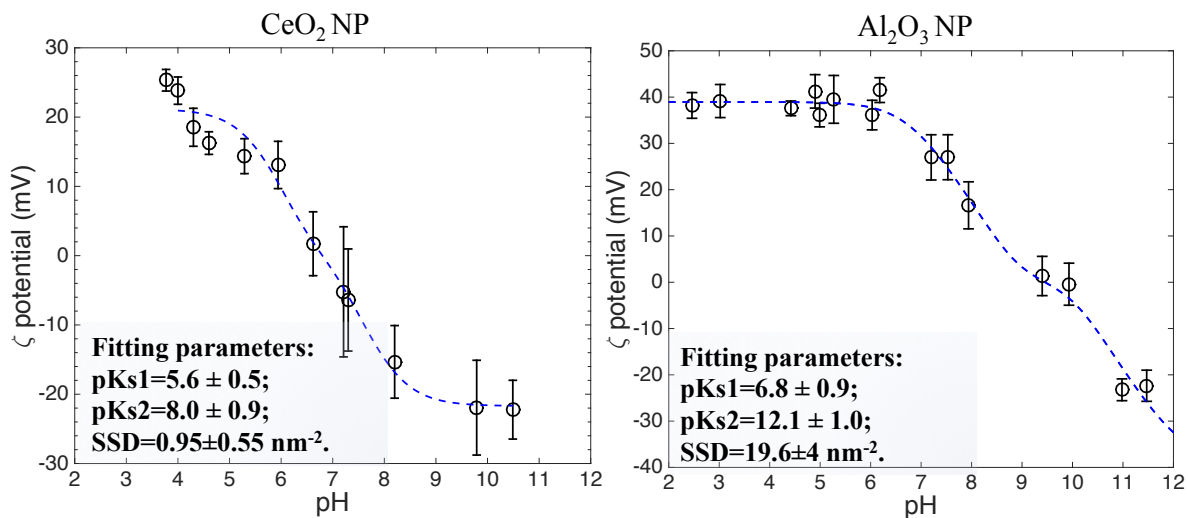


Figure S1. Zeta-potential of CeO₂ and Al₂O₃ NPs as a function of pH. The markers are the experimental measurement, and the solid line is the diffusive layer model fit (Table 1). The model fit parameterizes the pK_s values of surface $-OH$ groups and the surface site density (SSD), which are given with the charts.

Table S1. Hydrolysis of In(III), Ga(III) and As(V) ions and the equilibrium constants.

Equation	Equilibrium		
	Constant (logK)	Value	Source
$\text{HAsO}_4^{2-} \rightleftharpoons \text{H}^+ + \text{AsO}_4^{3-}$	$\log(K_1^{\text{As}})$	-11.6	Drever, 1997 ³
$\text{H}_2\text{AsO}_4^- \rightleftharpoons 2\text{H}^+ + \text{AsO}_4^{3-}$	$\log(K_2^{\text{As}})$	-18.36	Drever, 1997 ³
$\text{H}_3\text{AsO}_4 \rightleftharpoons 3\text{H}^+ + \text{AsO}_4^{3-}$	$\log(K_3^{\text{As}})$	-20.6	Drever, 1997 ³
$\text{In}^{3+} + \text{H}_2\text{O} \rightleftharpoons \text{In}(\text{OH})^{2+} + \text{H}^+$	$\log(K_1^{\text{In}})$	-3.48	Biryuk et al., 1986 ⁴
$\text{In}^{3+} + 2\text{H}_2\text{O} \rightleftharpoons \text{In}(\text{OH})_2^+ + 2\text{H}^+$	$\log(K_2^{\text{In}})$	-7.67	Biryuk et al., 1986 ⁴
$\text{In}^{3+} + 3\text{H}_2\text{O} \rightleftharpoons \text{In}(\text{OH})_3^+ + 3\text{H}^+$	$\log(K_3^{\text{In}})$	-12.75	Biryuk et al., 1986 ⁴
$\text{Ga}^{3+} + \text{H}_2\text{O} \rightleftharpoons \text{Ga}(\text{OH})^{2+} + \text{H}^+$	$\log(K_1^{\text{Ga}})$	-2.87	Biryuk and Nazarenko, 1973 ⁵
$\text{Ga}^{3+} + 2\text{H}_2\text{O} \rightleftharpoons \text{Ga}(\text{OH})_2^+ + 2\text{H}^+$	$\log(K_2^{\text{Ga}})$	-6.55	Biryuk and Nazarenko, 1973 ⁵
$\text{Ga}^{3+} + 3\text{H}_2\text{O} \rightleftharpoons \text{Ga}(\text{OH})_3^+ + 3\text{H}^+$	$\log(K_3^{\text{Ga}})$	-11.07	Biryuk and Nazarenko, 1973 ⁵
$\text{Ga}^{3+} + 4\text{H}_2\text{O} \rightleftharpoons \text{Ga}(\text{OH})_4^- + 4\text{H}^+$	$\log(K_4^{\text{Ga}})$	-17.3	Vagramjan and Leshawa, 1967 ⁶

Relate the surface site density (SSD) to the NP size for colloidal SiO₂ NPs

For a spherical colloidal SiO₂ NP, we denote p as the number of Si atoms across the diameter of the sphere, in the unit of nm⁻¹. The total number of Si atoms in this sphere is:

$$N_t = \frac{\pi \cdot p^3}{6} \quad \text{Eq(S1)}$$

where, N_t is the total number of Si in the sphere.

The weight of this SiO₂ NP is calculated as:

$$w_{NP} = \frac{N_t \cdot MW}{N_A} = \frac{\pi \cdot p^3 \cdot MW}{6N_A} \quad \text{Eq(S2)}$$

where, w_{NP} is the weight of the SiO₂ NP and MW is the molecular weight of SiO₂ (28.1 g • mol⁻¹).

w_{NP} is also calculated as:

$$w_{NP} = \rho \cdot \frac{1}{6} \cdot \pi \cdot d^3 \quad \text{Eq(S3)}$$

where ρ is the density of colloidal SiO₂ NPs and d is the particle diameter.

Eq(S2) and Eq(S3) give:

$$p = \left(\frac{\rho \cdot N_A}{MW} \right)^{\frac{1}{3}} \cdot d \quad \text{Eq(S4)}$$

For colloidal SiO₂ NPs, ρ is 2.2 g • cm⁻³ and MW is 28.1 g • mol⁻¹. Substituting these values into Eq(S4) gives:

$$p = 2.80d \quad \text{Eq(S5)}$$

where d is in nm.

Based on Eq(S1), the number of Si atom on the sphere surface (N_s) is calculated as:

$$N_s = \frac{1}{6} \pi (p^3 - (p-2)^3) \quad \text{Eq(S6)}$$

Given the assumption that each Si atom on the surface carries one –OH group, SSD is calculated as:

$$SSD = \frac{N_s}{\pi \cdot d^2} \quad \text{Eq(S7)}$$

Substituting Eq(S5) and Eq(S6) into Eq(S7) gives:

$$SSD = 7.86 + \frac{1.33}{d^2} - \frac{5.61}{d} \quad \text{Eq(S8)}$$

where d is in nm.

References

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